

### **Advance Technical Information**

# X-Class HiPerFET™ Power MOSFET

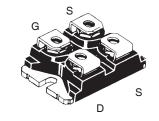
## IXFN90N85X

N-Channel Enhancement Mode Avalanche Rated Fast Intrinsic Diode



V <sub>DSS</sub>	=	850V
I <sub>D25</sub>	=	90A
R <sub>DS(on)</sub>	≤	$41 \text{m}\Omega$





G = Gate	D = Drain
S = Source	

Symbol	Test Conditions		Maximum Ratings		
V <sub>DSS</sub> V <sub>DGR</sub>	$T_{J} = 25^{\circ}\text{C to } 150^{\circ}$ $T_{J} = 25^{\circ}\text{C to } 150^{\circ}$		850 850	V	
V <sub>GSS</sub> V <sub>GSM</sub>	Continuous Transient		± 30 ± 40	V	
I <sub>D25</sub>	$T_c = 25^{\circ}C$ $T_c = 25^{\circ}C$ , Pulse	Width Limited by T <sub>JM</sub>	90 180	A A	
I <sub>A</sub> E <sub>AS</sub>	$T_c = 25^{\circ}C$ $T_c = 25^{\circ}C$		45 4	A J	
$P_{D}$	T <sub>C</sub> = 25°C		1200	W	
dv/dt	$I_{\rm S} \le I_{\rm DM}, V_{\rm DD} \le V_{\rm DSS}, T_{\rm J} \le 150^{\circ}{\rm C}$		50	V/ns	
T <sub>J</sub> T <sub>JM</sub> T <sub>stg</sub>			-55 +150 150 -55 +150	0° 0° 0°	
V <sub>ISOL</sub>	50/60 Hz, RMS I <sub>ISOL</sub> ≤ 1mA	t = 1 minute t = 1 second	2500 3000	V~ V~	
M <sub>d</sub>	Mounting Torque Terminal Connect		1.5/13 1.3/11.5	Nm/lb.in Nm/lb.in	
Weight			30	g	

### **Features**

- International Standard Package
- miniBLOC, with Aluminium Nitride Isolation
- Isolation Voltage 2500V~
- High Current Handling Capability
- Fast Intrinsic Diode
- Avalanche Rated
- Low R<sub>DS(on)</sub>

#### **Advantages**

- High Power Density
- Easy to Mount
- Space Savings

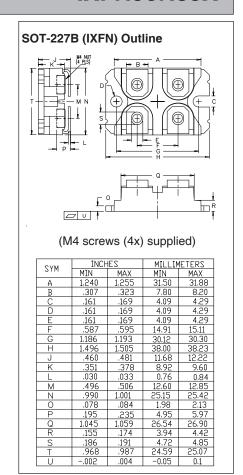
#### **Applications**

- Switch-Mode and Resonant-Mode Power Supplies
- DC-DC Converters
- PFC Circuits
- AC and DC Motor Drives
- Robotics and Servo Controls

		cteristic Values Typ.   Max.				
BV <sub>DSS</sub>	$V_{GS} = 0V, I_D = 3mA$		850			V
V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 8mA$		3.5		5.5	V
I <sub>GSS</sub>	$V_{GS} = \pm 30V, V_{DS} = 0V$				± 200	nA
I <sub>DSS</sub>	$V_{DS} = V_{DSS}, V_{GS} = 0V$	T <sub>J</sub> = 125°C			50 5	μA mA
R <sub>DS(on)</sub>	$V_{GS} = 10V, I_{D} = 45A, Note 1$	1			41	mΩ



Symbol Test Conditions (T <sub>J</sub> = 25°C, Unless Otherwise Specified)		Char Min.	aracteristic Values   Typ.   Max		
g <sub>fs</sub>	$V_{DS} = 10V, I_{D} = 45A, Note 1$	37	62	S	
$R_{Gi}$	Gate Input Resistance		0.60	Ω	
C <sub>iss</sub>			13.3	nF	
C <sub>oss</sub>	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		13.0	nF	
C <sub>rss</sub>			220	pF	
	Effective Output Capacitance				
$C_{o(er)}$	Energy related $\begin{cases} V_{GS} = 0V \\ V_{DS} = 0.8 \cdot V_{DSS} \end{cases}$		395	pF	
$\mathbf{C}_{o(tr)}$	Time related $\int V_{DS} = 0.8 \cdot V_{DSS}$		1820	pF	
t <sub>d(on)</sub>	Resistive Switching Times		50	ns	
t, }	$V_{GS} = 10V$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_{D} = 45A$		20	ns	
t <sub>d(off)</sub>	$R_{\rm G} = 10$ (External)		126	ns	
t,	$n_{\rm G} = 152  (\text{External})$		8	ns	
$Q_{g(on)}$			340	nC	
Q <sub>gs</sub>	$V_{GS} = 10V$ , $V_{DS} = 0.5 \bullet V_{DSS}$ , $I_D = 45A$		78	nC	
Q <sub>gd</sub>			190	nC	
R <sub>thJC</sub>				0.104 °C/W	
R <sub>thCS</sub>			0.05	°C/W	



#### Source-Drain Diode

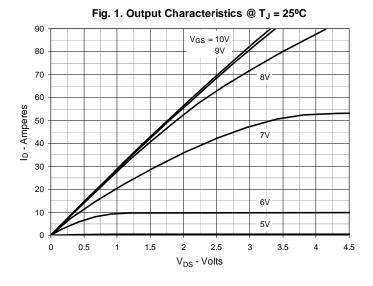
Symbol Test Conditions		Characteristic Values			
$(T_J = 25^{\circ}C)$	, Unless Otherwise Specified)	Min.	Тур.	Max.	
I <sub>s</sub>	$V_{GS} = 0V$			90	A
I <sub>SM</sub>	Repetitive, Pulse Width Limited by $T_{_{JM}}$			360	Α
V <sub>SD</sub>	$I_F = I_S$ , $V_{GS} = 0V$ , Note 1			1.4	V
t <sub>rr</sub>	$I_{\rm E} = 45A$ , -di/dt = 200A/ $\mu$ s		250		ns
Q <sub>RM</sub>	,		5.3		μC
I <sub>RM</sub>	$V_{R} = 100V, V_{GS} = 0V$		42.0		Α

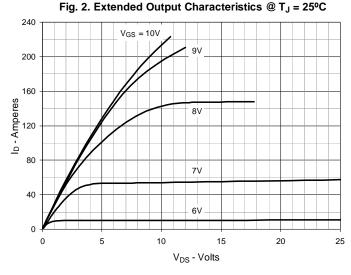
Note 1. Pulse test,  $t \le 300\mu s$ , duty cycle,  $d \le 2\%$ .

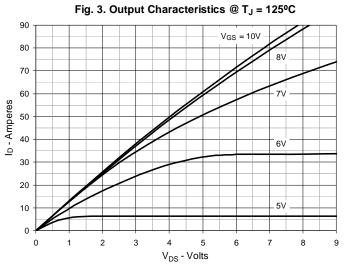
#### **ADVANCE TECHNICAL INFORMATION**

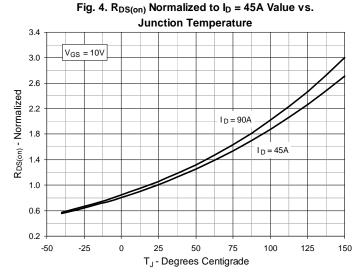
The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

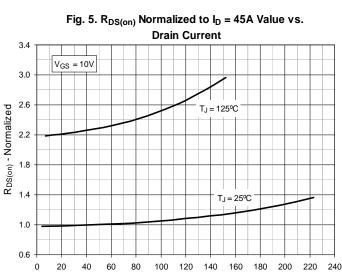




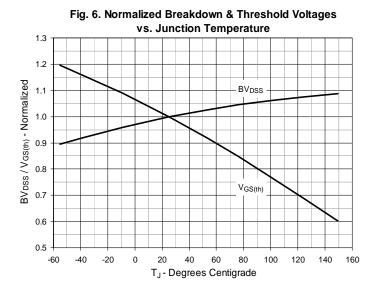




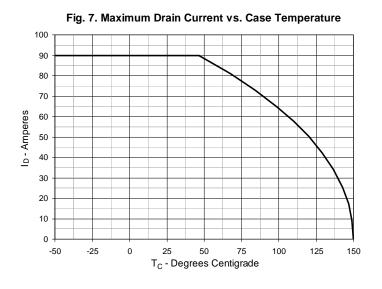


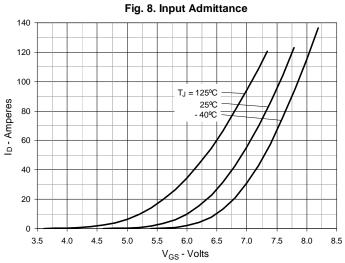


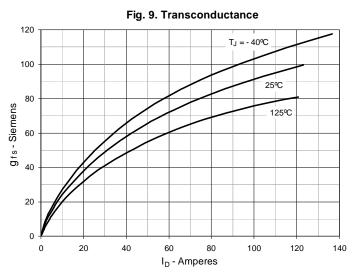
I<sub>D</sub> - Amperes

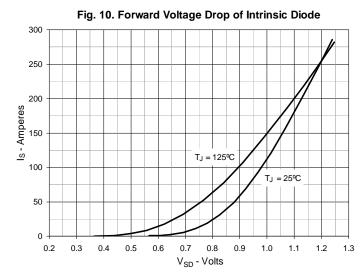


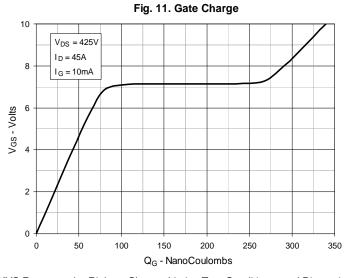


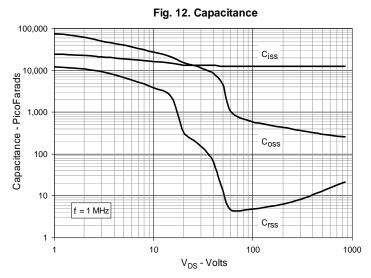






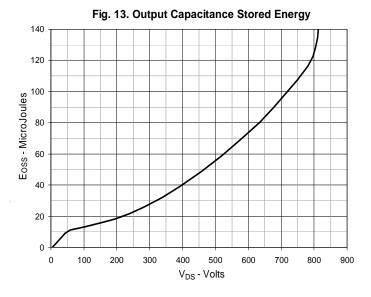






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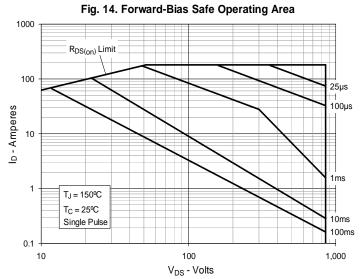


Fig. 15. Maximum Transient Thermal Impedance

